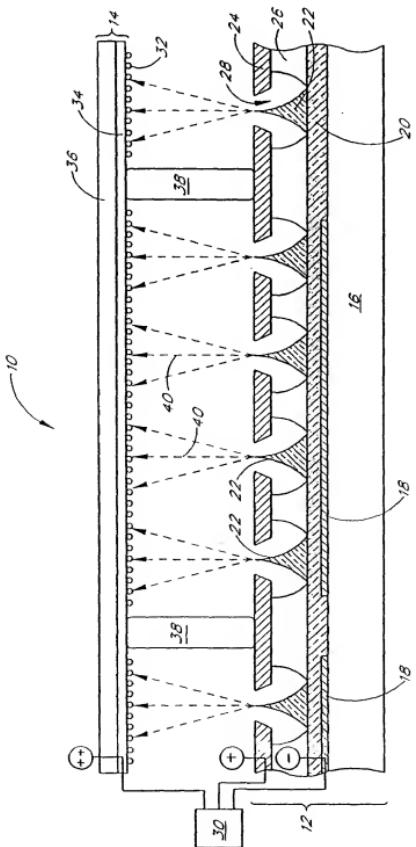


NITROGEN AND PHOSPHORUS DOPED AMORPHOUS SILICON AS
RESISTOR FOR FIELD EMISSION DISPLAY DEVICE BASEPLATE

Raina, et al.
Appl. No.: Unknown Atty Docket: MICRON.111CI



F/G. 1

(PRIOR ART)

**NITROGEN AND PHOSPHORUS DOPED AMORPHOUS SILICON AS
RESISTOR FOR FIELD EMISSION DISPLAY DEVICE BASEPLATE**

Appl. No.: Unknown *Atty Docket: MICRON.111CI*

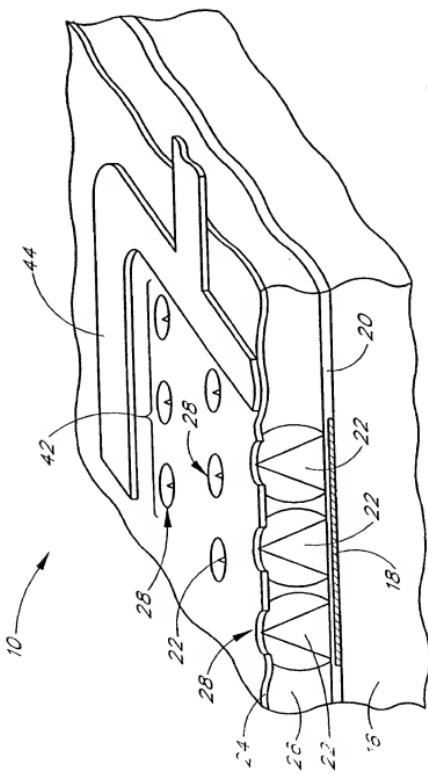


FIG. 2

(PRIOR ART)

NITROGEN AND PHOSPHORUS DOPED AMORPHOUS SILICON AS
RESISTOR FOR FIELD EMISSION DISPLAY DEVICE BASEPLATE

Raina, et al.

Appl. No.: Unknown Atty Docket: MICRON.IIIIC1

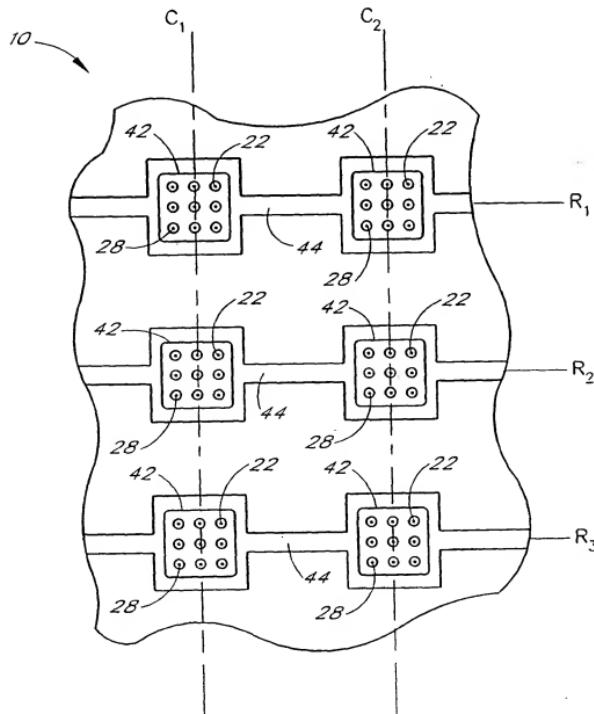


FIG. 3

(PRIOR ART)

NITROGEN AND PHOSPHORUS DOPED AMORPHOUS SILICON AS
RESISTOR FOR FIELD EMISSION DISPLAY DEVICE BASEPLATE

Raina, et al.

Appl. No.: Unknown Atty Docket: MICRON.111C1

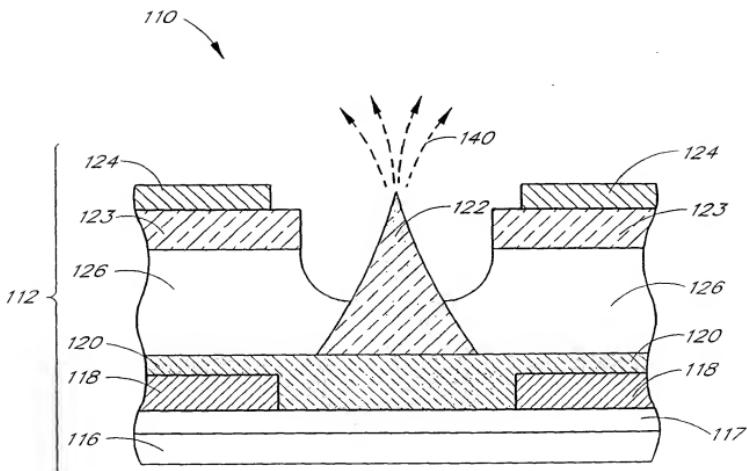


FIG. 4

NITROGEN AND PHOSPHORUS DOPED AMORPHOUS SILICON AS
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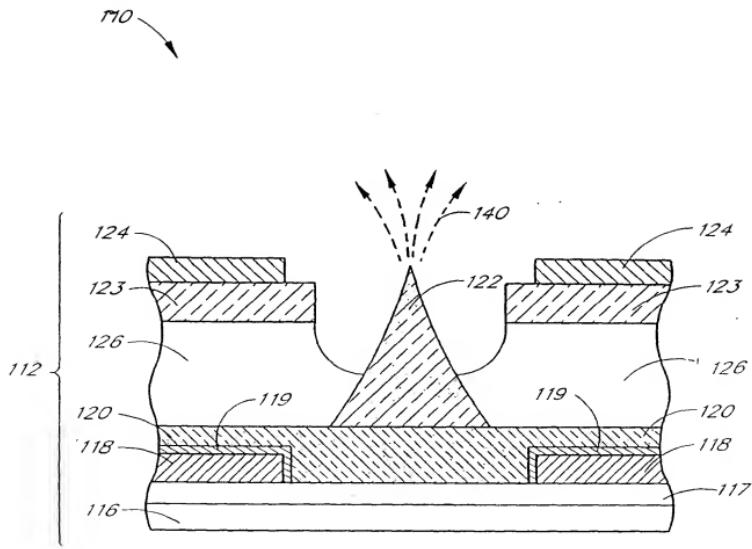


FIG. 5